

| | Hits | Search Text | DBs | Time Stamp |
|----|--------|--|-----------------|------------------|
| 1 | 39262 | polyimide | USPAT; US-PGPUB | 2001/10/02 14:12 |
| 2 | 39953 | silicon adj nitride | USPAT; US-PGPUB | 2001/10/02 16:25 |
| 3 | 228818 | semiconductor | USPAT; US-PGPUB | 2001/10/02 16:30 |
| 4 | 229194 | electrode | USPAT; US-PGPUB | 2001/10/02 16:30 |
| 5 | 81460 | insulat\$3 adj (layer or film) | USPAT; US-PGPUB | 2001/10/02 16:42 |
| 6 | 4611 | ((insulat\$3 adj (layer or film)) same polyimide | USPAT; US-PGPUB | 2001/10/02 16:42 |
| 7 | 2816 | semiconductor and ((insulat\$3 adj (layer or film)) same polyimide) | USPAT; US-PGPUB | 2001/10/02 16:42 |
| 8 | 740 | (semiconductor and ((insulat\$3 adj (layer or film)) same polyimide)) and (silicon adj nitride) and electrode | USPAT; US-PGPUB | 2001/10/02 16:43 |
| 9 | 5006 | bonding adj pad | USPAT; US-PGPUB | 2001/10/02 16:43 |
| 10 | 248 | (semiconductor and ((insulat\$3 adj (layer or film)) same polyimide)) and (bonding adj pad) | USPAT; US-PGPUB | 2001/10/02 16:43 |
| 11 | 49 | ((semiconductor and ((insulat\$3 adj (layer or film)) same polyimide)) and (silicon adj nitride) and electrode) and (bonding adj pad) | USPAT; US-PGPUB | 2001/10/02 16:54 |
| 12 | 37465 | parasitic | USPAT; US-PGPUB | 2001/10/02 16:45 |
| 13 | 395 | (semiconductor and ((insulat\$3 adj (layer or film)) same polyimide)) and parasitic | USPAT; US-PGPUB | 2001/10/02 16:45 |
| 14 | 32 | ((semiconductor and ((insulat\$3 adj (layer or film)) same polyimide)) and parasitic) and (bonding adj pad) | USPAT; US-PGPUB | 2001/10/02 16:45 |
| 15 | 2085 | polyimide same (silicon adj nitride) | USPAT; US-PGPUB | 2001/10/02 16:54 |
| 16 | 1517 | (polyimide same (silicon adj nitride)) and semiconductor | USPAT; US-PGPUB | 2001/10/02 16:54 |
| 17 | 941 | ((polyimide same (silicon adj nitride)) and semiconductor) and (insulat\$3 adj (layer or film)) | USPAT; US-PGPUB | 2001/10/02 16:55 |
| 18 | 587 | ((polyimide same (silicon adj nitride)) and semiconductor) and ((insulat\$3 adj (layer or film)) same polyimide) | USPAT; US-PGPUB | 2001/10/02 16:55 |
| 19 | 397 | (((polyimide same (silicon adj nitride)) and semiconductor) and ((insulat\$3 adj (layer or film)) same polyimide)) and electrode | USPAT; US-PGPUB | 2001/10/02 16:55 |
| 20 | 46 | (((polyimide same (silicon adj nitride)) and semiconductor) and ((insulat\$3 adj (layer or film)) same polyimide)) and (bonding adj pad) | USPAT; US-PGPUB | 2001/10/02 16:55 |
| 21 | 5006 | bonding adj pad | USPAT; US-PGPUB | 2001/10/03 11:14 |
| 22 | 39262 | polyimide | USPAT; US-PGPUB | 2001/10/03 11:14 |
| 23 | 81460 | insulat\$3 adj (layer or film) | USPAT; US-PGPUB | 2001/10/03 11:22 |
| 24 | 583 | (bonding adj pad) same (insulat\$3 adj (layer or film)) | USPAT; US-PGPUB | 2001/10/03 11:23 |
| 25 | 4611 | polyimide same (insulat\$3 adj (layer or film)) | USPAT; US-PGPUB | 2001/10/03 11:23 |
| 26 | 117 | ((bonding adj pad) same (insulat\$3 adj (layer or film))) and (polyimide same (insulat\$3 adj (layer or film))) | USPAT; US-PGPUB | 2001/10/03 11:23 |